# Development of coated conductors based on IBAD MgO

Paul Arendt - MgO template development for coated conductors using ion-beam assisted deposition

Steve Foltyn - High current YBCO on IBAD MgO by pulsed laser deposition

\$1850 K, 6.0 FTE

Superconductivity Technology Center Los Alamos National Laboratory





# MgO template development for coated conductors using ion-beam assisted deposition

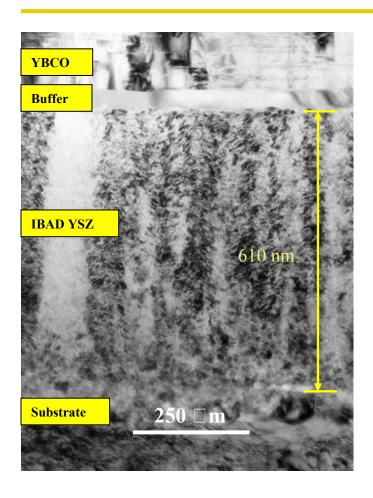
Paul Arendt, Steve Foltyn, Ray DePaula, Randy Groves, Terry Holesinger, Quanxi Jia, Sascha Kreiskott Vladimir Matias, Liliana Stan, Igor Usov, Haiyan Wang

> Superconductivity Technology Center Los Alamos National Laboratory

- 1. Substrate cation diffusion barrier
- 2. IBAD MgO texture optimization
  - a) nucleation layer
  - b) assist ion beam divergence

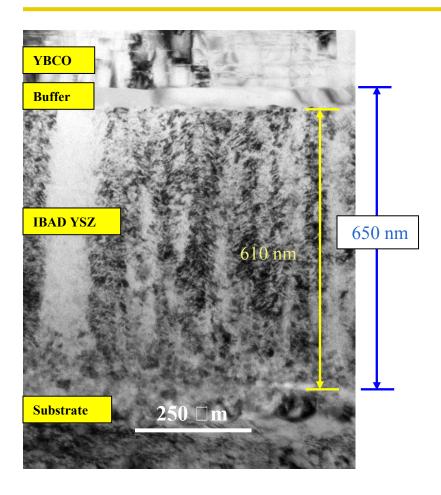






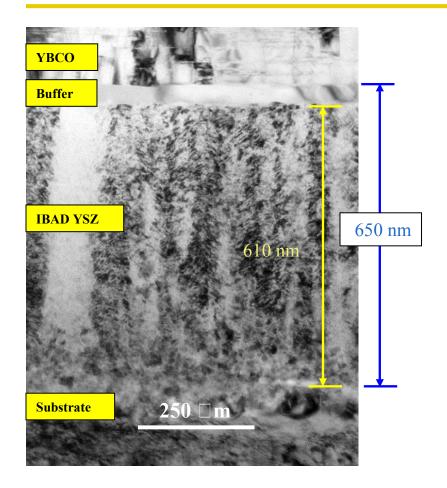


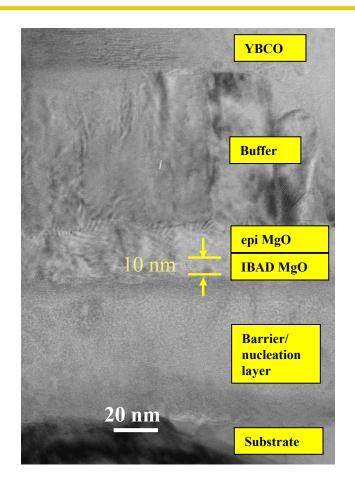






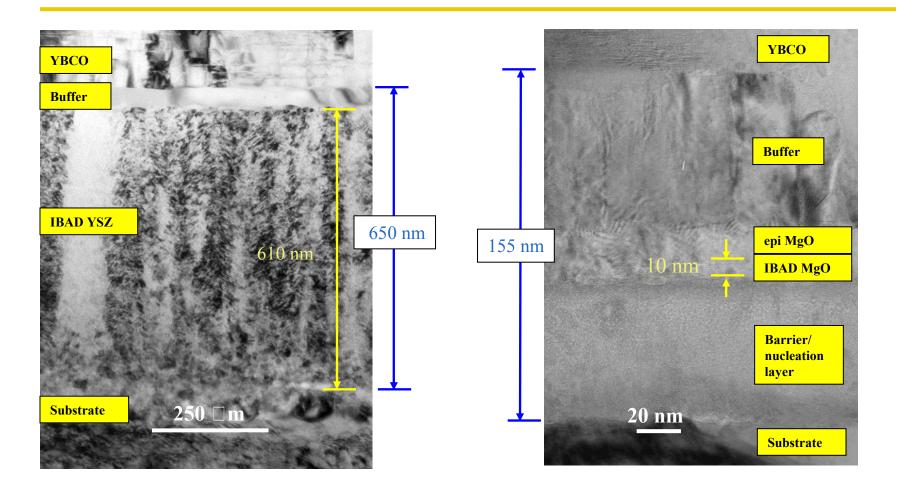








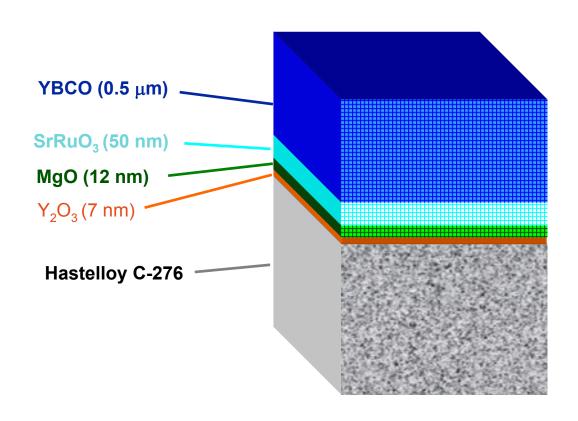








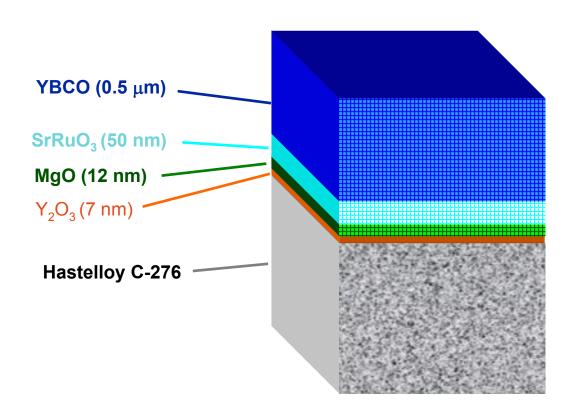
#### Why have a barrier layer?







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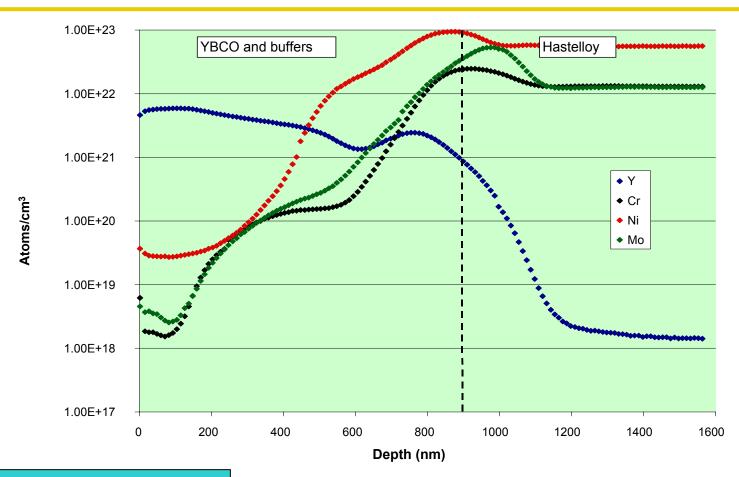








#### SIMS depth profile of selected cations



YBCO/SRO/MgO/Y<sub>2</sub>O<sub>3</sub>/Hastelloy





Substrate cation diffusion is thought to be resolved for IBAD YSZ with its thicker template/buffer architecture





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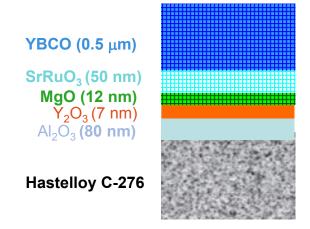




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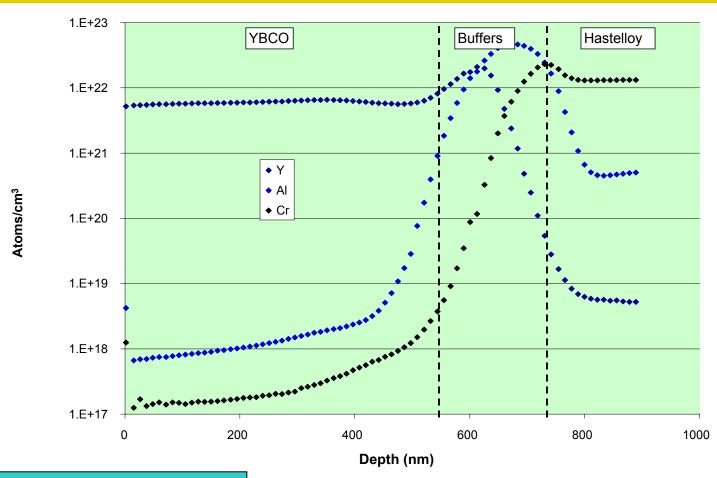
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# SIMS depth profile of selected cations with alumina layer deposited on substrate

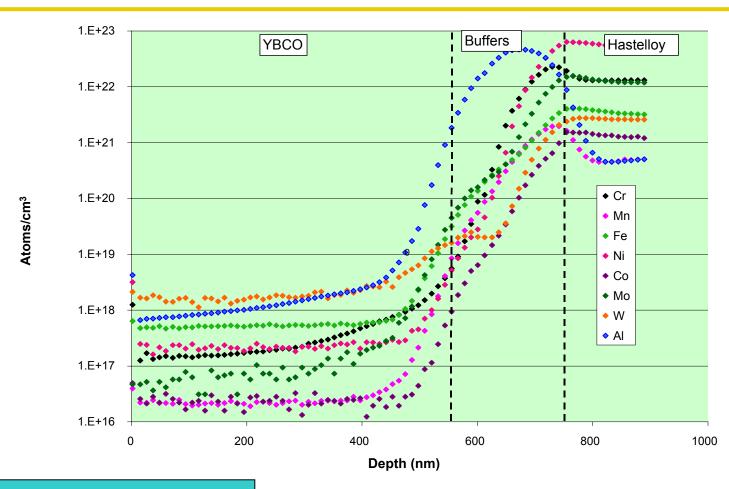


YBCO/SRO/MgO/Y<sub>2</sub>O<sub>3</sub>/Al<sub>2</sub>O<sub>3</sub>/Hastelloy





# All the substrate cations are impeded from diffusing into the YBCO

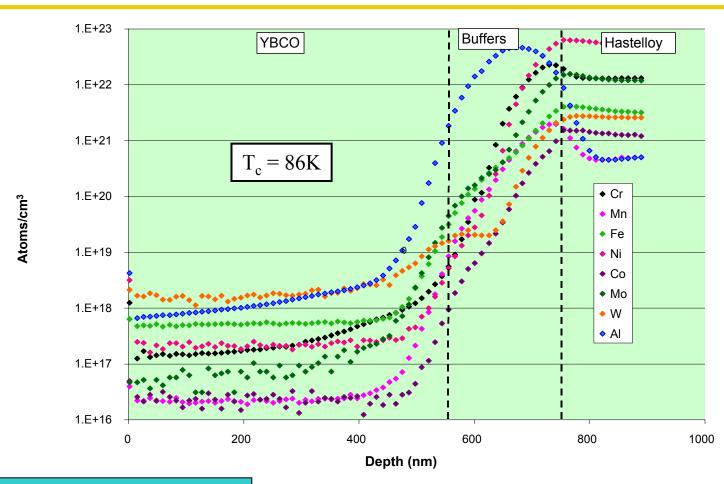


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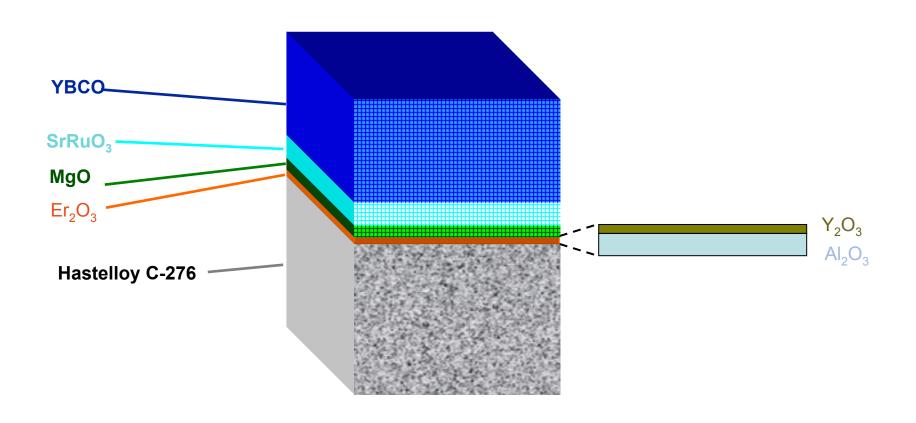


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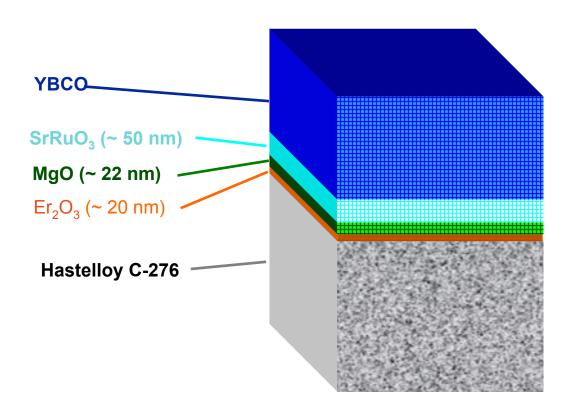
# Another approach for MgO templates is to combine the barrier and nucleation layers







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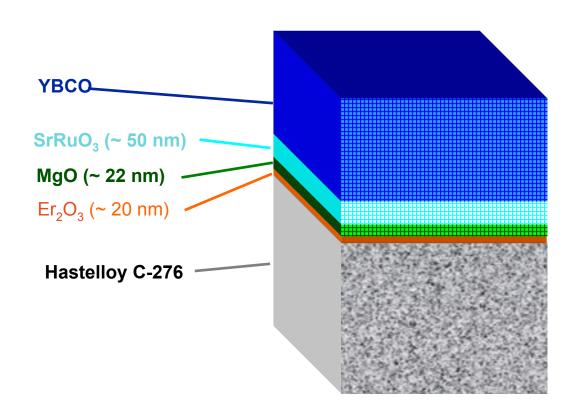


 $T_c = 89.5 \text{ K}$ 





# Another approach for MgO templates is to combine the barrier and nucleation layers



$$T_c = 89.5 \text{ K}$$

 $J_c(75K,sf) = 2.3 \text{ MA/cm}^2$ (thickness = 1.7 µm)





- 1. Substrate cation diffusion barrier
- 2. IBAD MgO texture optimization a) nucleation layer
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# IBAD MgO texture vs. thickness processing window is extended when deposited on yttria

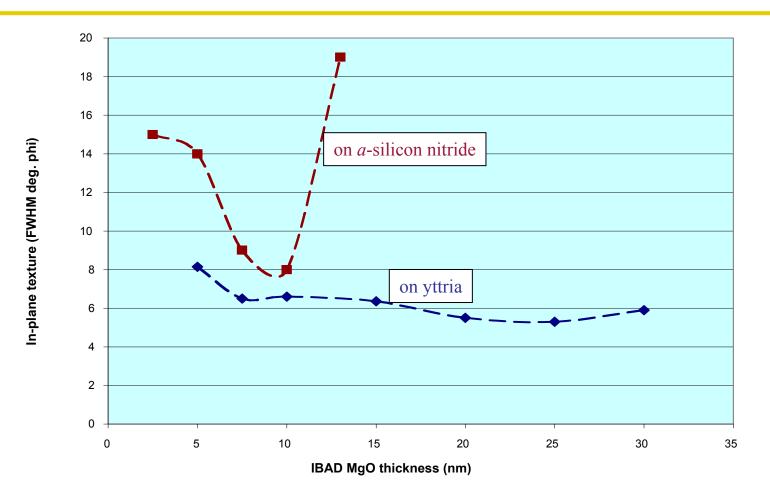
In-plane texture (FWHM deg. phi) on *a*-silicon nitride 

IBAD MgO thickness (nm)





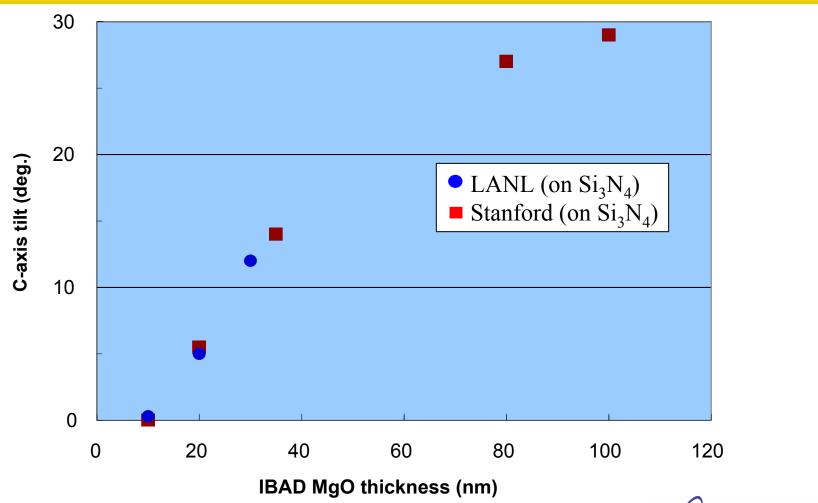
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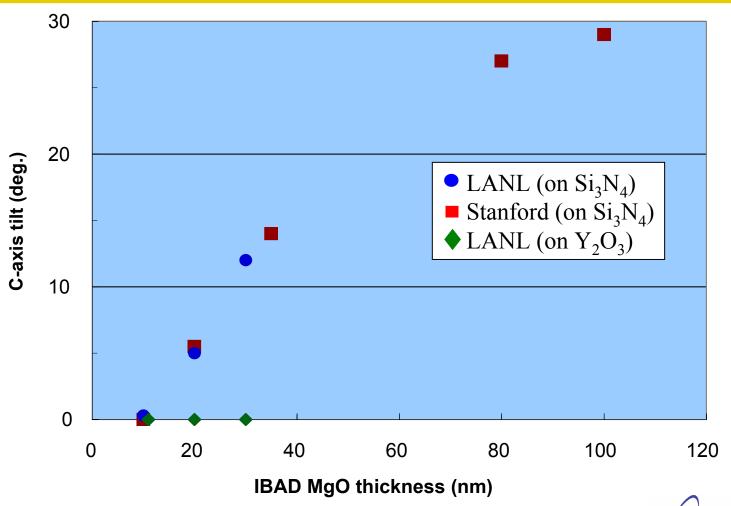
# C-axis tilt for IBAD MgO on $Si_3N_4$ believed to be reason for texture degradation when thickness > 100 Å







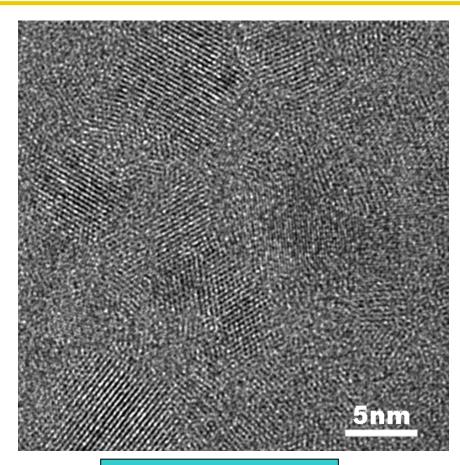
# No c-axis tilt observed for IBAD MgO on $Y_2O_3$ (up to 300 Å)







# Plan view HRTEM reveals the yttria nucleation layer to be nanocrystalline

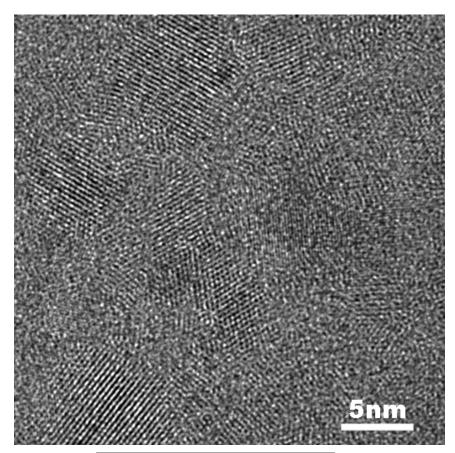


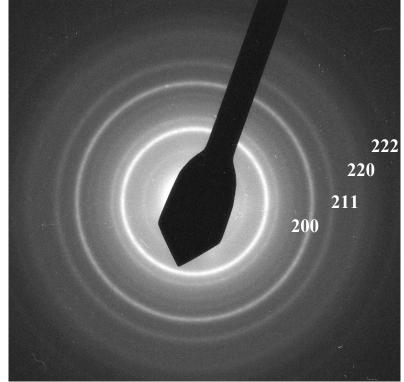
10 nm thick Y<sub>2</sub>O<sub>3</sub> film





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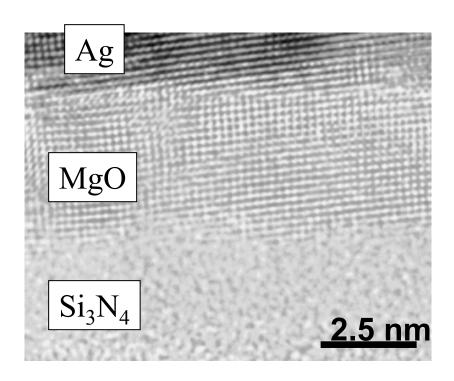
10 nm thick Y<sub>2</sub>O<sub>3</sub> film

SAD pattern shows film is randomly oriented





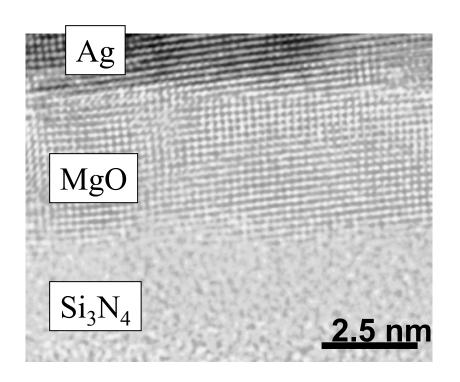
### Comparison of HRTEM cross sections reveal differing growth characteristics for IBAD MgO on the two nucleation layers

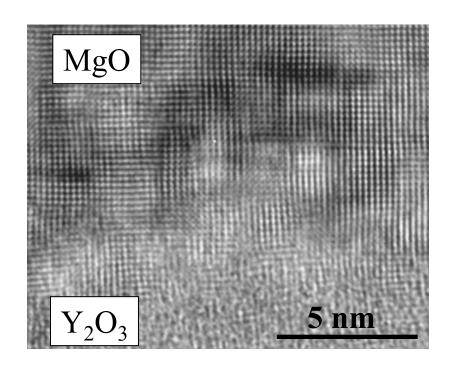






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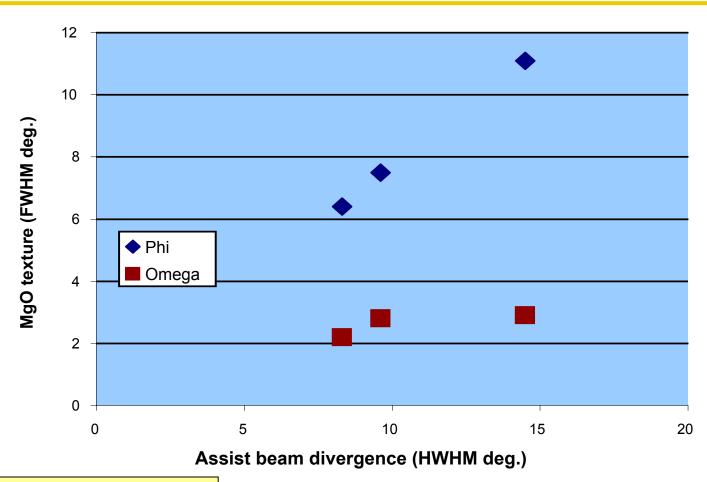


- 1. Substrate cation diffusion barrier
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# IBAD MgO texture is improved with decreased assist ion beam divergence

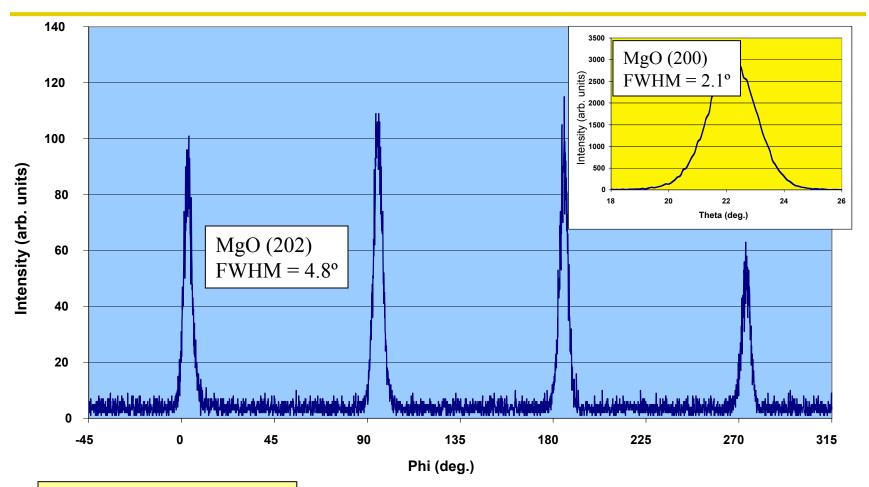


Homoepi MgO/IBAD MgO/Y<sub>2</sub>O<sub>3</sub>/Si





# Assist beam optimization experiments led to improved texture for IBAD MgO templates

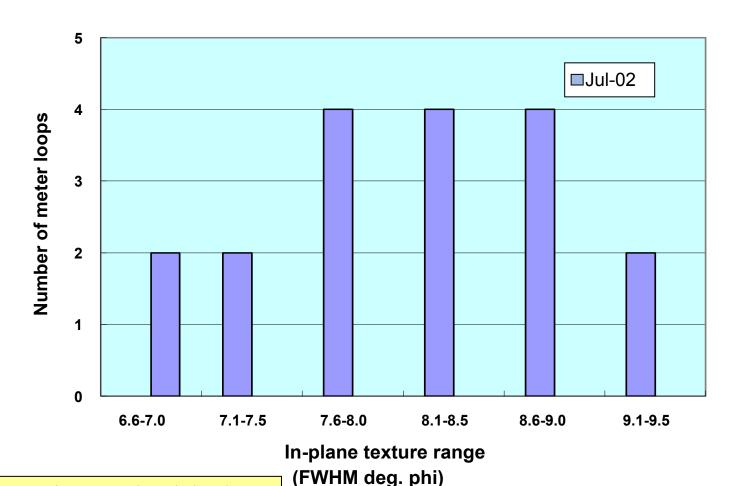


Homoepi MgO/IBAD MgO/Y<sub>2</sub>O<sub>3</sub>/Si





#### IBAD MgO in-plane texture - reproducibility of continuously processed meter loops

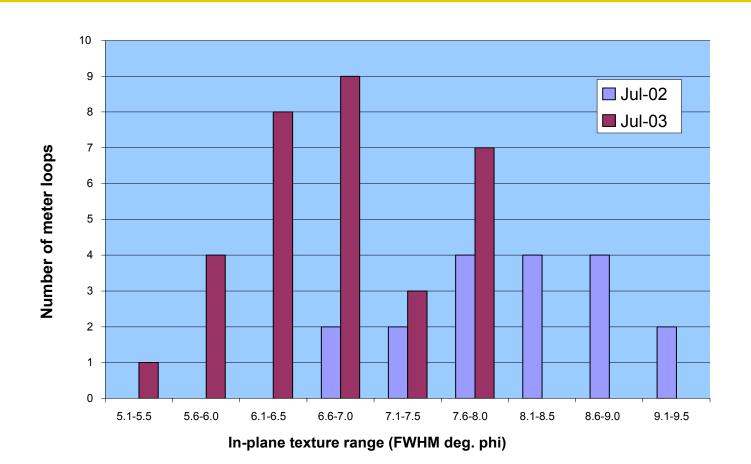


Homoepi MgO/IBAD MgO/Y<sub>2</sub>O<sub>3</sub>/ Al<sub>2</sub>O<sub>3</sub> /C-276

UC University
of California

Los Alamos

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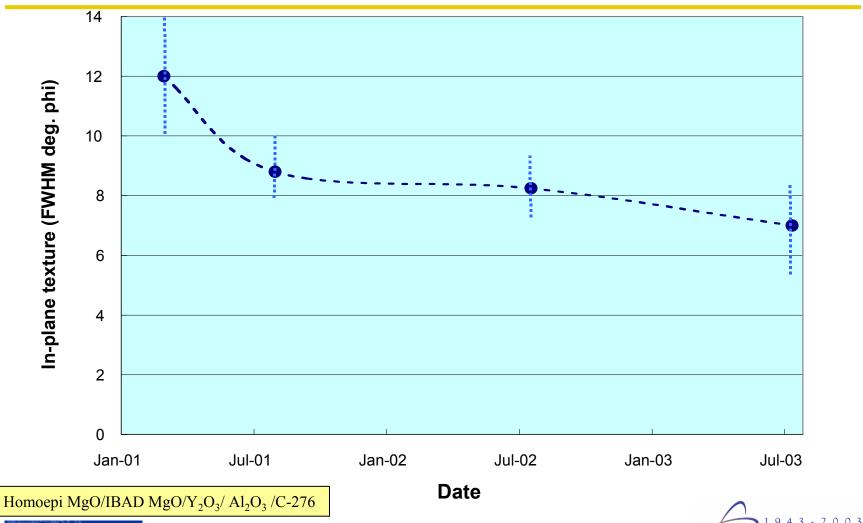


Homoepi MgO/IBAD MgO/Y<sub>2</sub>O<sub>3</sub>/ Al<sub>2</sub>O<sub>3</sub> /C-276



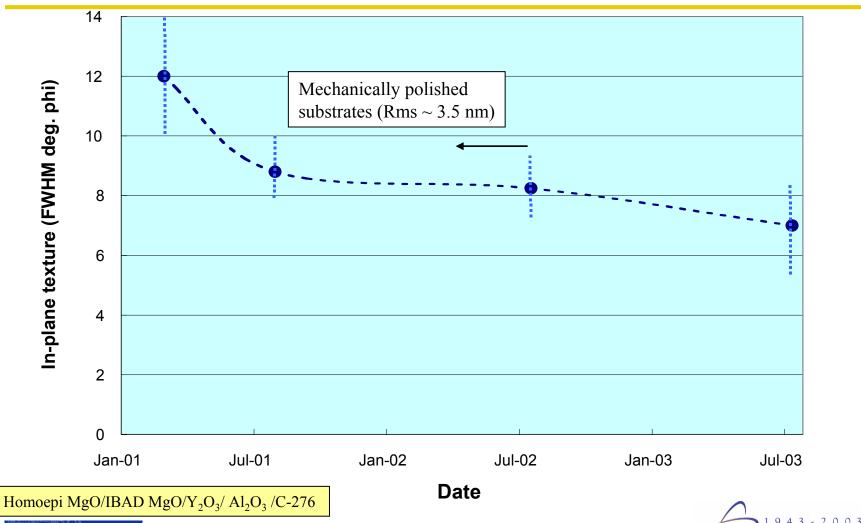


# Texture history for continuously processed IBAD MgO templates



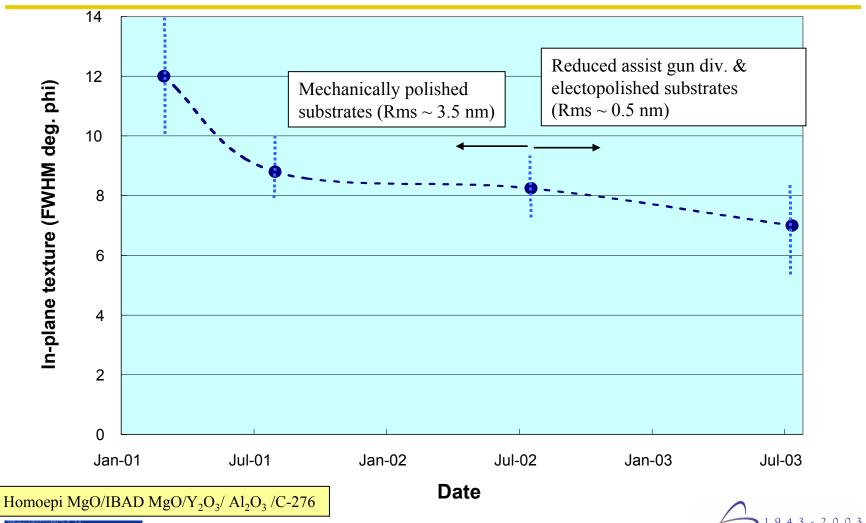


# Texture history for continuously processed IBAD MgO templates





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### **Summary**

- ➤ Alumina inhibits diffusion of substrate cations to the YBCO layer
- Yttria extends the thickness window for IBAD MgO processing
- Erbia combines the barrier and nucleation properties of the alumina and yttria layers
- ➤ Reduction of the assist ion gun divergence leads to improved IBAD MgO texture
- Average in-plane texture of continuously processed meters has improved since FY02 by 1.5°





## High current YBCO on IBAD MgO by pulsed laser deposition

Steve Foltyn, Paul Arendt, Leonardo Civale, Yates Coulter, Ray DePaula, Paul Dowden, Randy Groves, Quanxi Jia, Yuan Li, Boris Maiorov, Liliana Stan, Haiyan Wang

Superconductivity Technology Center Los Alamos National Laboratory

Judith MacManus-Driscoll (visiting staff member) – *University of Cambridge*Jodi Reeves – *SuperPower, Inc.* 

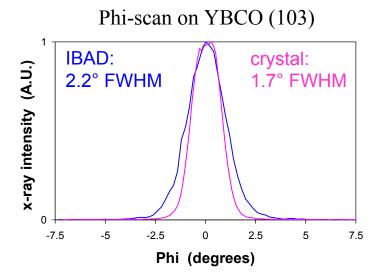
- 1. YBCO on IBAD MgO with near-single-crystal texture
- 2. High critical current YBCO on IBAD MgO
- 3. High I<sub>c</sub> continuously processed tapes

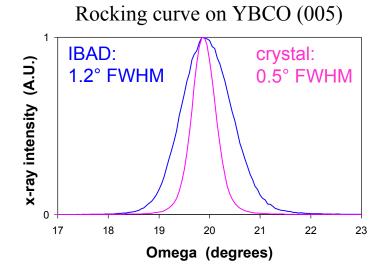




### Improved alignment in IBAD MgO has enabled the achievement of near-single-crystal texture for YBCO

With IBAD MgO texture in the 7° FWHM range, YBCO texture is approaching that measured on single crystal MgO (YBCO thickness: ~1.8 µm)

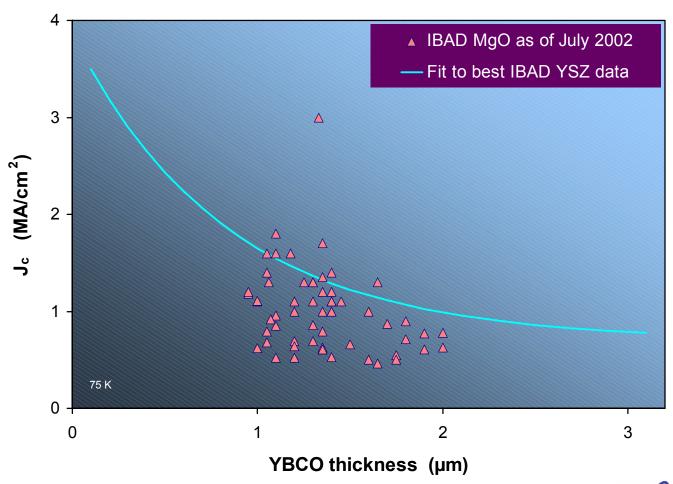








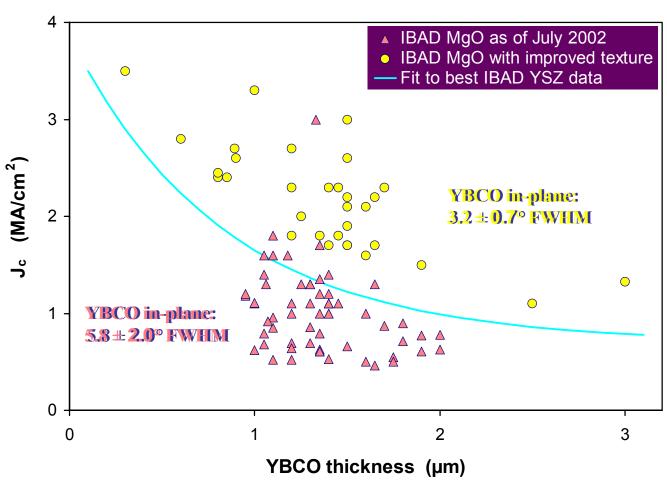
### Last year, our J<sub>c</sub> levels for IBAD MgO samples were generally below those for IBAD YSZ ...







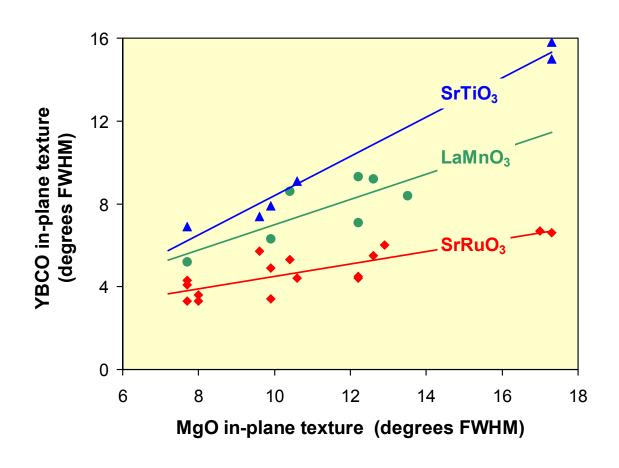
### ... but improved in-plane texture now routinely yields higher performance







### Part of the performance increase resulted from switching the buffer material from SrRuO<sub>3</sub> to SrTiO<sub>3</sub>



Because SrTiO<sub>3</sub> does not improve YBCO texture as much as LaMnO<sub>3</sub> or SrRuO<sub>3</sub>, its use is not feasible unless the IBAD MgO texture is less than ~ 8° FWHM.

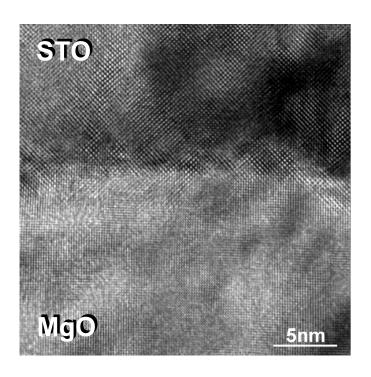
Data presented at 2002 Peer Review

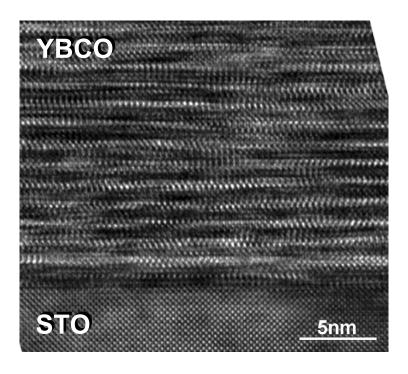




### SrTiO<sub>3</sub> is a chemically stable buffer material that readily aligns on MgO and is an excellent lattice match for YBCO

High-resolution TEM cross-sections from an IBAD MgO sample reveal that both the top and bottom interfaces of the SrTiO<sub>3</sub> buffer layer are smooth and free of reaction products.

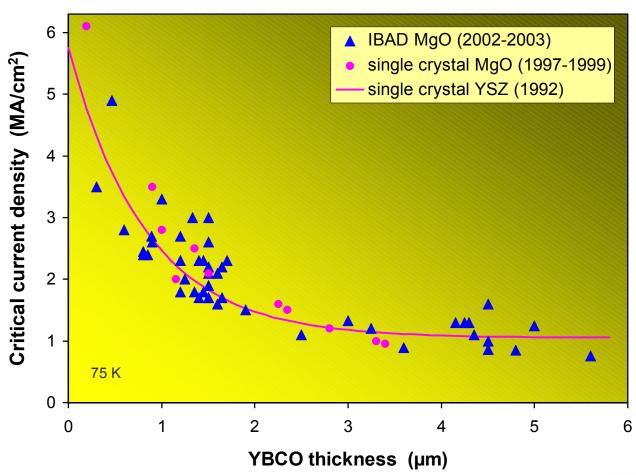








### Improved texture yields IBAD MgO J<sub>c</sub>s that are comparable to those for single-crystal substrates

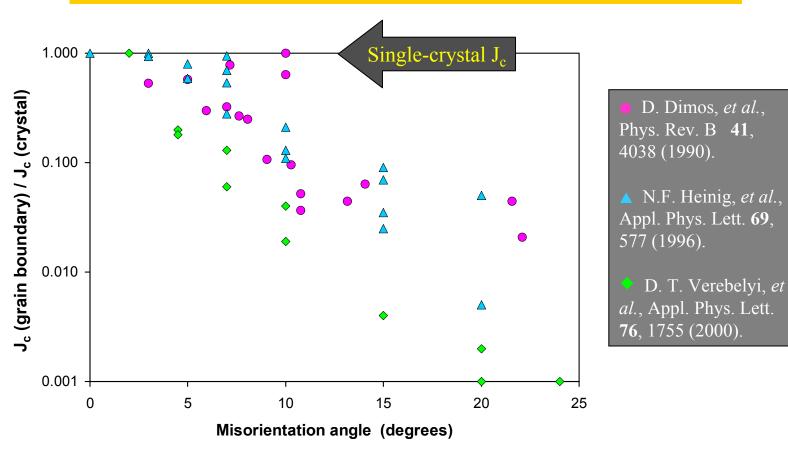






### One argument is that the often-observed bicrystal plateau occurs in coated conductors, too

In bicrystals, perfect alignment is not needed to reach single crystal J<sub>c</sub> levels

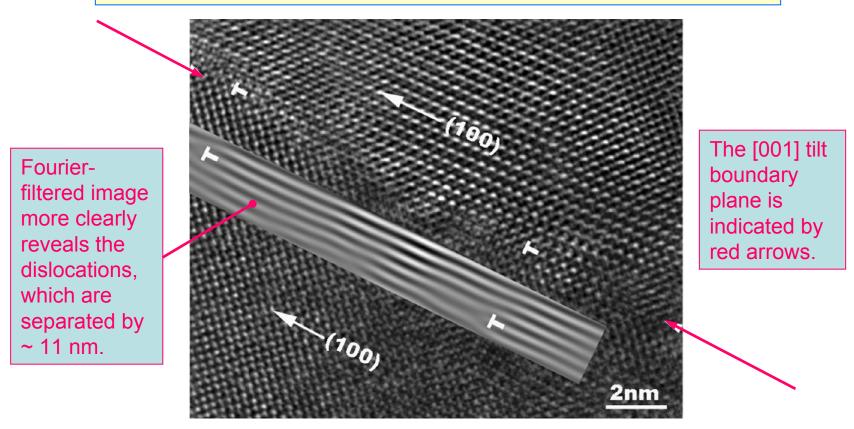






### YBCO crystallinity is barely disrupted in very low angle grain boundaries

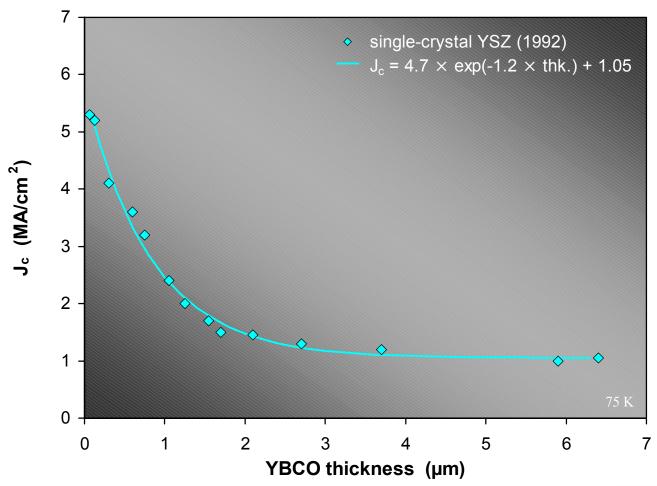
Plan-view TEM showing 2.2 degree grain boundary in YBCO on IBAD MgO







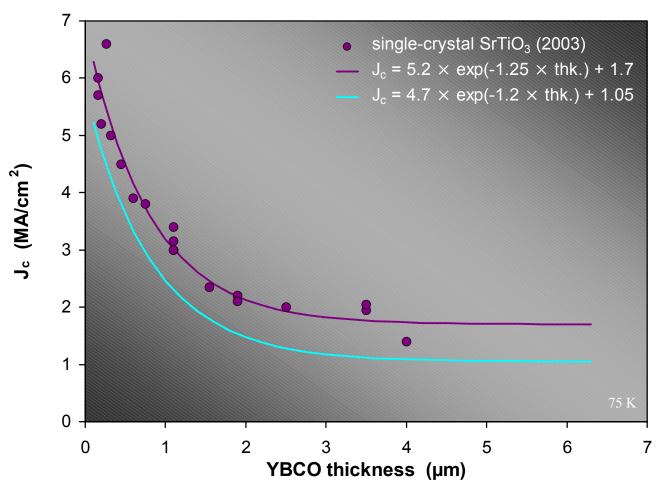
### Another argument is that the 1992 single-crystal curve is an outdated benchmark ...







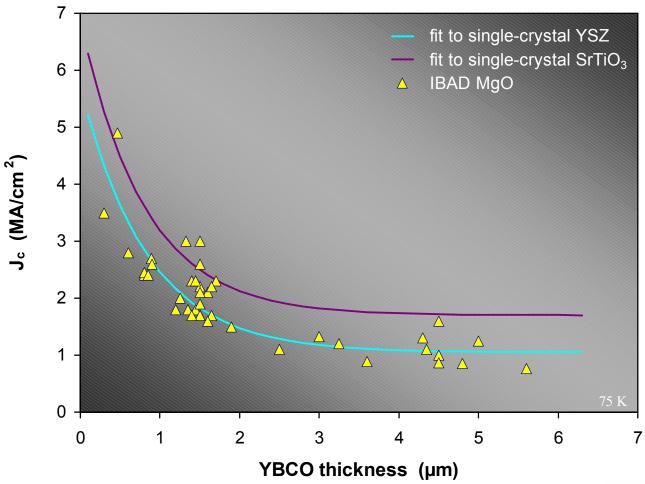
### ... so a more modern data set was obtained using the best possible substrate: single-crystal SrTiO<sub>3</sub>







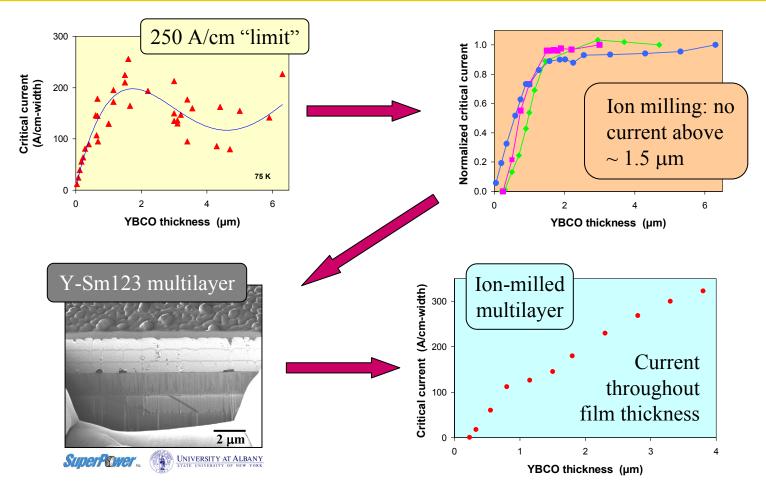
### And the highest IBAD MgO J<sub>c</sub>s still compare favorably with this new benchmark







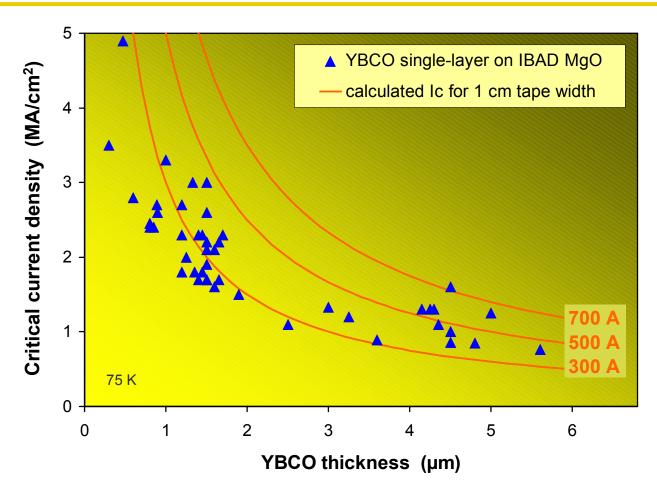
### We previously reported that we needed multilayers to reach I<sub>c</sub>s over ~ 250 A/cm-width on IBAD YSZ;







### however, with IBAD MgO, multilayers are not needed to reach high current levels

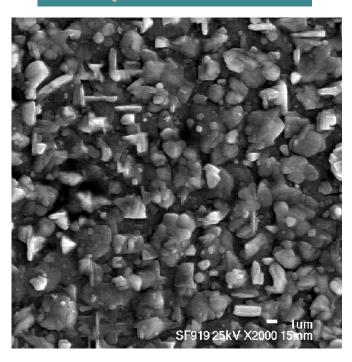




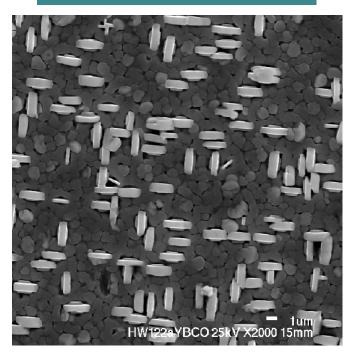


### The difference is likely due to the smoother substrate, which reduces cumulative roughening of the YBCO

3.0  $\mu$ m YBCO on IBAD YSZ  $J_c = 0.6 \text{ MA/cm}^2$ 



4.5  $\mu$ m YBCO on IBAD MgO  $J_c = 1.6 \text{ MA/cm}^2$ 

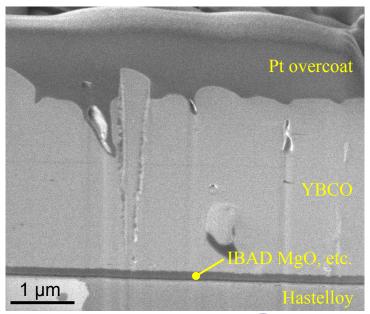






### Focused ion beam cross-section shows a dense microstructure, largely free of porosity

Cross-section (viewed at 45°) of a 4.5  $\mu$ m YBCO film with  $J_c > 1.0 \text{ MA/cm}^2$ 



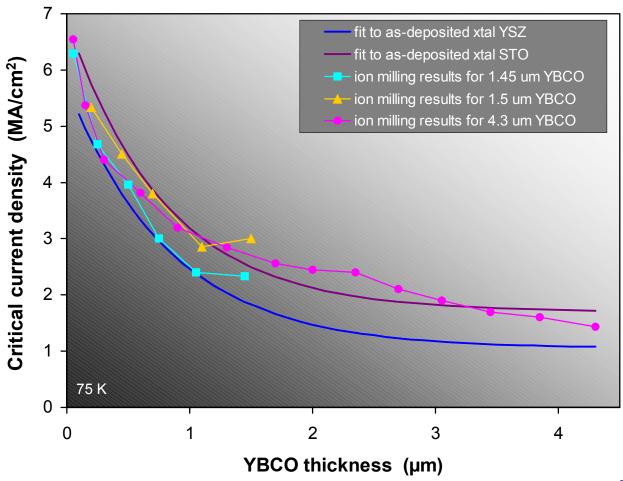








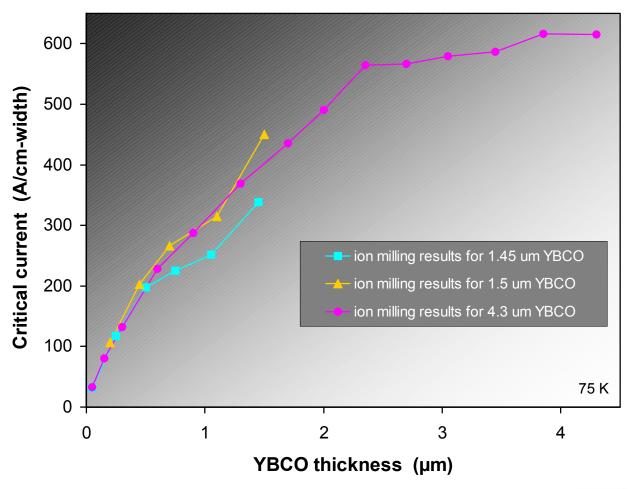
### Ion milling shows that the dense structure allows J<sub>c</sub> to remain high throughout the film thickness ...







### ... and allows I<sub>c</sub> to continue increasing well beyond 1.5 microns of film thickness







#### Scoring criterion: FY 2003 Performance

"Optimize the thickness of each layer in the IBAD MgO architecture with a goal of reducing the total nonsuperconducting layer thickness to below 100 nm without reducing performance."

- Determined that  $T_c < 75$  K unless the  $Al_2O_3$  barrier layer is used initially concluded that the  $Al_2O_3$  cannot be eliminated.
- SIMS analysis revealed that this layer greatly reduces but does not eliminate diffusion of substrate elements into the YBCO, so we were reluctant to reduce barrier layer thickness.
- Recent ion milling results indicate that a certain amount of diffusion can be tolerated, so thickness reduction may be possible after all.
- Found that the  $Al_2O_3$  barrier layer and the  $Y_2O_3$  nucleation layer can be replaced by a single, 20nm layer of  $Er_2O_3$  for a total nonsuperconducting layer thickness of 92 nm.  $J_c$ : 2.3 MA/cm<sup>2</sup> @ 1.7  $\mu$ m.

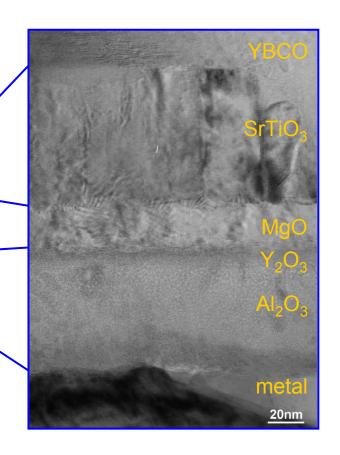




However, the Er<sub>2</sub>O<sub>3</sub> layer substitution has thus far produced mixed results; for now, our preferred architecture is:

YBCO	<u>1-5 μm</u> /
<u>SrTiO</u> <sub>3</sub>	70 nm
homoepitaxial MgO	13 nm
IBAD MgO	<u> 10 nm</u>
Y <sub>2</sub> O <sub>3</sub> nucleation layer	7 nm
Al <sub>2</sub> O <sub>3</sub> barrier layer	<u>55 nm</u>
Hastelloy C-276 substrate	<u>100 μm</u>

Total nonsuperconducting layer thickness: 155 nm







"Support both IGC and the Research Park in scaling up the latest IBAD and PLD technologies."

- Continued IBAD and PLD technology transfer to SuperPower via frequent communication, site visits, sample and data exchange, and licensing of intellectual property.
- SuperPower has made substantial progress this year, as outlined in their presentation on Wednesday.
- Supported the Research Park through regular interactions, technician support, and equipment loans; also collaborated on small-sample and tape test runs to confirm performance of Research Park IBAD MgO and PLD buffer layers.
- All substrate tape used in the Core Program was reel-to-reel electropolished by Research Park personnel.





"Distribute IBAD MgO to our industrial partners and national laboratory collaborators for deposition of YBCO, and work with them individually to achieve optimum performance with their respective deposition processes."

- Sent samples of IBAD MgO with various buffer layers to American Superconductor, and assisted in the development of AMSC's CeO<sub>2</sub> cap layer.
- Also sent IBAD MgO samples to Oak Ridge for deposition of LaMnO<sub>3</sub> these samples were then sent to AMSC for MOD YBCO.
- Pest results for batch-processed samples (0.8-0.9 μm YBCO, 5 mm wide):
  - With  $SrRuO_3/CeO_2$  up to 1.8 MA/cm<sup>2</sup> (~ 140 A/cm-width)
  - With LaMnO<sub>3</sub>/CeO<sub>2</sub> up to 2.6 MA/cm<sup>2</sup> ( $\sim 200$  A/cm-width)





- Sent IBAD MgO tapes of various lengths to SuperPower, Inc., initially with a SrRuO<sub>3</sub> buffer layer, more recently with SrTiO<sub>3</sub>.
- Provided information about our PLD YBCO deposition conditions in order to facilitate optimization at SuperPower.
- Best results for 1-cm-wide continuously processed tape:
  - $\bullet$  I<sub>c</sub> values of 100 150 A on 3-5 cm lengths.
  - $\bullet$  J<sub>c</sub> of 1.5MA/cm<sup>2</sup> on 0.9  $\mu$ m thick YBCO
  - $\bullet$  Data from seven runs with average I<sub>c</sub> of 128 A ± 14 A





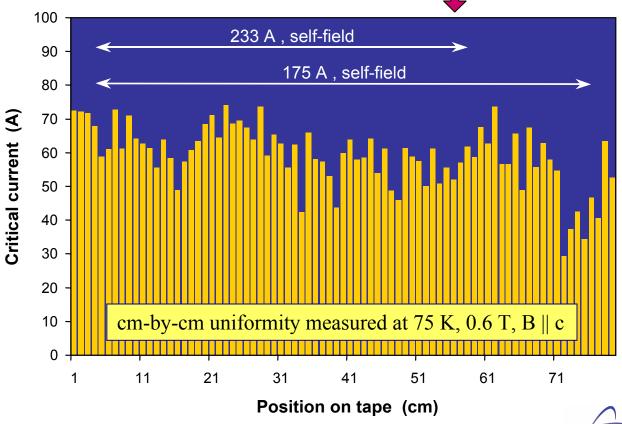
"Solve the problem(s) preventing us from achieving high-current YBCO on IBAD MgO/SrRuO<sub>3</sub> (Goal: 100 A in a meter) ..."

- As expected, the primary obstacle to high I<sub>c</sub> with continuous processing was the PLD tape-coater, and *not* the IBAD MgO itself.
- The main difficulty was lack of reproducibility, which was traced to building cooling water temperature that exceeded laser specifications at irregular intervals.
- Once this was fixed (with a chilled water recirculator), optimization of laser deposition parameters proceeded normally.
- After optimization, five short tapes ( $\sim$  20 cm coated,  $\sim$  10 cm measured) were produced. I<sub>c</sub>s were 265, 276, 292, 298, and 319 A (75K, self field, one centimeter width).





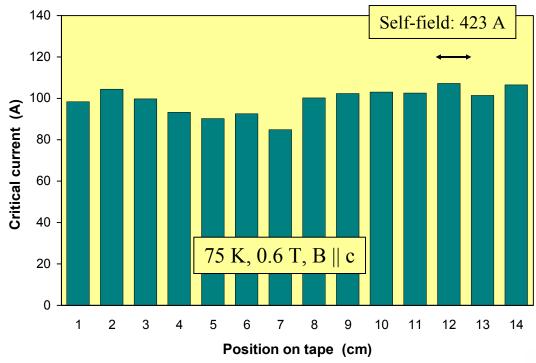
Our first two longer lengths have self-field I<sub>c</sub>s of 173 A over 70 cm, and 175 A over 72 cm (with 233 A over 54 cm).





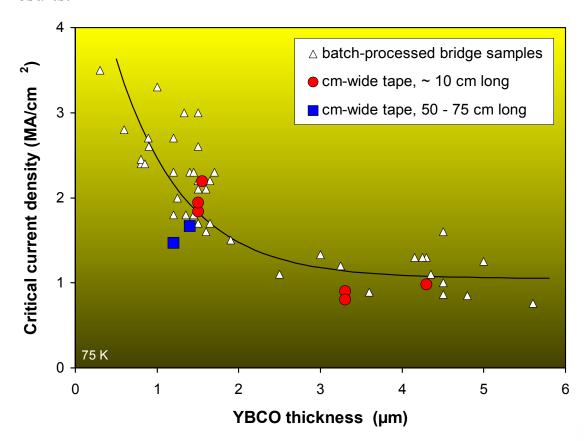
" ...and incorporate multilayer technology to reach 200 A in an IBAD MgO meter."

Since multilayers are no longer necessary, we tried simply making the YBCO thicker (4.3 μm) with the following result:





Continuously processed tape J<sub>c</sub>s are comparable to batch-processed bridge results.





"Deposit YBCO on meter lengths of IBAD MgO with the Oak Ridge LaMnO<sub>3</sub> buffer layer. Goal: 100 A."

- Based in part on good results obtained with Oak Ridge-sputtered LMO, the Research Park team has been routinely depositing LMO on their IBAD MgO, so we collaborated on this using RP IBAD MgO/LMO rather than duplicate the LMO effort in the Core Program.
- Several bridge samples were prepared with an average YBCO thickness of 1.3 μm, and an average J<sub>c</sub> of 1.1 MA/cm<sup>2</sup> (140 A/cm-width). Best results were obtained with SrRuO<sub>3</sub> on top of the LaMnO<sub>3</sub>.
- With SrTiO<sub>3</sub> on top of the Research Park's IBAD/LMO, we reached an I<sub>c</sub> of 251 A in a cm-wide x 4.5 cm long tape.





#### Scoring criterion: Research Integration

- Distributed buffered IBAD MgO samples to SuperPower, Inc. and American Superconductor, and worked with each to assist in the deposition of high-quality YBCO on these samples. This is a successful first step in the transfer of IBAD MgO technology to industry, and also demonstrates the utility of this technology for two very different YBCO deposition methods (PLD and MOD).
- Renewed our CRADA with SuperPower, Inc. and signed a new CRADA with American Superconductor, both will support coated conductor activities in industry.
- Engaged in sample and information exchanges with Oak Ridge, Argonne, and Brookhaven National Laboratories, leading to joint publications. Results from some of these collaborations are being reported this week in the Strategic Research Session.





#### Scoring criterion: Research Integration (continued)

- Began a formal relationship with Lawrence Berkeley National Laboratory to draw on their long-standing expertise in IBAD with a PLD vapor source. The purpose is to analyze differences in films deposited with this technique in order to better understand the IBAD process in general. Initial results were reported by LBNL yesterday.
- Fourteen of 25 Core Program publications since 2002 are the result of joint activities with national laboratories and companies, as well as six universities





#### Scoring criterion: FY 2003 Results

- 1. Improved the MgO texture on meter-long tapes to  $\sim 7^{\circ}$  FWHM, enabling the deposition of YBCO with in-plane texture of less than 3° FWHM. This resulted in  $J_c$  values exceeding those on our best IBAD YSZ and equal to those for single-crystal substrates.
- 2. Analyzed diffusion of substrate elements into the YBCO and found that  $Al_2O_3$  is an effective diffusion barrier. Also found that  $Er_2O_3$  can be an effective barrier with the potential for replacing both  $Al_2O_3$  and  $Y_2O_3$ . This will allow us to reduce the number of nonsuperconducting layers.
- 3. Ion-milling experiments showed that thinned films and as-deposited films have the same J<sub>c</sub> vs. thickness dependence. They also revealed no adverse effect of substrate elements diffusing into the YBCO, *suggesting that barrier and buffer layer thicknesses can be reduced*.



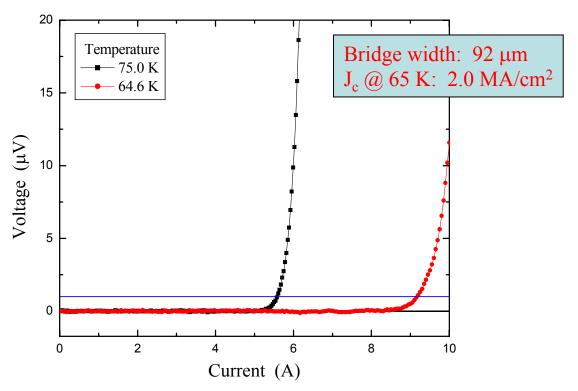


- 4. Made a transition from SrRuO<sub>3</sub> to SrTiO<sub>3</sub> as the buffer layer between MgO and YBCO, with an improvement in performance. STO is less expensive, more chemically stable, and can be fabricated into a more robust PLD target than SRO.
- 5. Discovered that the porosity problems found in thick YBCO on IBAD YSZ do not exist with IBAD MgO; believe this is due to the smoother substrate surface used for the latter. We no longer need the Y-Sm multilayers, described in previous years, for thick, high-current films.
- 6. Produced many thick film bridge samples on IBAD MgO with  $I_c > 300$  A/cm-width. The best result is an  $I_c$  of 720 A/cm-width (4.5  $\mu$ m, 1.6  $MA/cm^2$ ).





7. A 5  $\mu$ m thick film – with a  $J_c$  of 1.2 MA/cm<sup>2</sup> @ 75 K – was measured in pumped liquid nitrogen. Result:  $I_c$  (65 K) = 1000 A/cm-width.





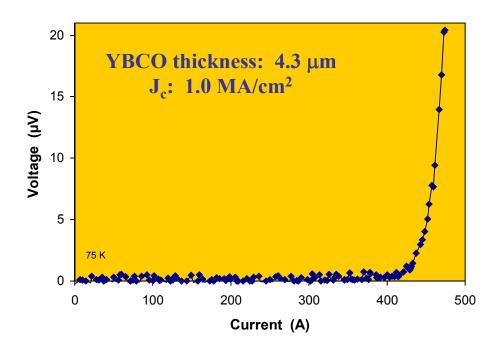


- 8. Summary of cm-wide, continuously processed tape:
  - Five 10-cm-long tapes with  $I_c$ s of 265-319 A, and  $J_c$ s of 0.9 2.2 MA/cm<sup>2</sup>.
  - \* Two ~ 70-cm-long tapes with  $I_c$ s of 173 and 175 A.
  - $\star$  A 54-cm section of one of the above tapes with  $I_c = 233$  A.





- 9. Deposited a thick film on IBAD MgO tape with the following result:
  - \* 80 100 A at 0.6 T, B||c over 14 cm
  - ❖ Same tape, self field − 423 A over 1 cm







- 10. Our industrial partners were successful in depositing high-current YBCO on Los Alamos-supplied IBAD MgO.
  - American Superconductor reached 200 A/cm-width on small, batch processed samples with MOD YBCO. This demonstrates that IBAD MgO is a viable coated conductor technology for ex-situ YBCO processing.
  - SuperPower, Inc. reproducibly achieved 100-150 A on cm-wide, continuously processed tapes. This is the latest accomplishment in the ongoing technology transfer of our IBAD and PLD processes to SuperPower through a CRADA.





#### Scoring criterion: FY 2004 Plans

In FY 2004 the Core Program will substantially reduce its effort in the continuous processing of meter-long tapes, in order to focus on more basic and long-range issues that can impact both cost and performance of IBAD-based coated conductors.

- Experimentally investigate the fundamental texturing mechanisms of IBAD. Goal: Develop a model that will allow us to further refine IBAD deposition parameters and texture.
- Use extended I-V curves for IBAD MgO to evaluate the validity of the bicrystal plateau analogy for coated conductors. *Goal: Determine whether improved texture will yield higher J\_cs*.





#### Scoring criterion: FY 2004 Plans (continued)

- Approach the drop in  $J_c$  with thickness as though it is a materials-processing issue, and not intrinsic. At a particular thickness, maximize  $J_c$  through a comprehensive process optimization. Goal: Reproducible achievement of  $I_c$ s over 400 A/cm-width at a film thickness of  $\leq 1.5 \ \mu m$ .
- Design and implement systematic experiments to determine if chemical modifications to REBCO offer enhanced performance, particularly in an external magnetic field. *Goal: Reproducibly double J<sub>c</sub> at 75 K in a magnetic field parallel to the c-axis.*
- Use ion-milling and SIMS to determine the quantitative tolerance of YBCO to diffusing substrate materials, and use this information to minimize the nonsuperconducting layer thickness. *Goal:* < 100 nm.





#### Scoring criterion: FY 2004 Plans (continued)

- Develop a single material that can serve as both a barrier and nucleation layer. Goal: Reduce the number of layers by one, and reduce the barrier/nucleation layer thickness by 20 nm, with no reduction in performance.
- Continue using our 1 meter tape capability to supply IBAD MgO to industrial partners and other national laboratories, and work with them individually to achieve optimum YBCO performance. *Goal: Three organizations depositing YBCO with J<sub>c</sub>s equivalent to those on single-crystal substrates.*





#### **Conclusions**

- IBAD MgO is an industrially-scalable process that involves a commercial alloy substrate, electropolishing, and less than 160 nm of deposited material between the metal and YBCO.
- From microbridges through meter lengths, we are achieving higher YBCO J<sub>c</sub>s and higher cm-wide I<sub>c</sub>s on IBAD MgO than we ever did on IBAD YSZ.
- We believe that there remain several areas in which the IBAD MgO structure can be simplified and superconductor performance on IBAD MgO can be enhanced we will focus on these areas in FY 2004.
- The first step in transferring IBAD MgO technology to industry was very successful, and this transfer will continue next year.



